NSN 5962-01-263-9403

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No



View Online at https://aerobasegroup.com/nsn/5962-01-263-9403

Body Length:
Between 0.640 inches and 0.662 inches
Body Width:
Between 0.640 inches and 0.662 inches
Body Height:
Between 0.064 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
38 input
Case Outline Source And Designator:
C-5 mil-m-38510
Current Rating Per Characteristic:
10.00 microamperes forward current, nonrepetitive, peak total value minor
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
8.0 volts power source
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:
44 leadless
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

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